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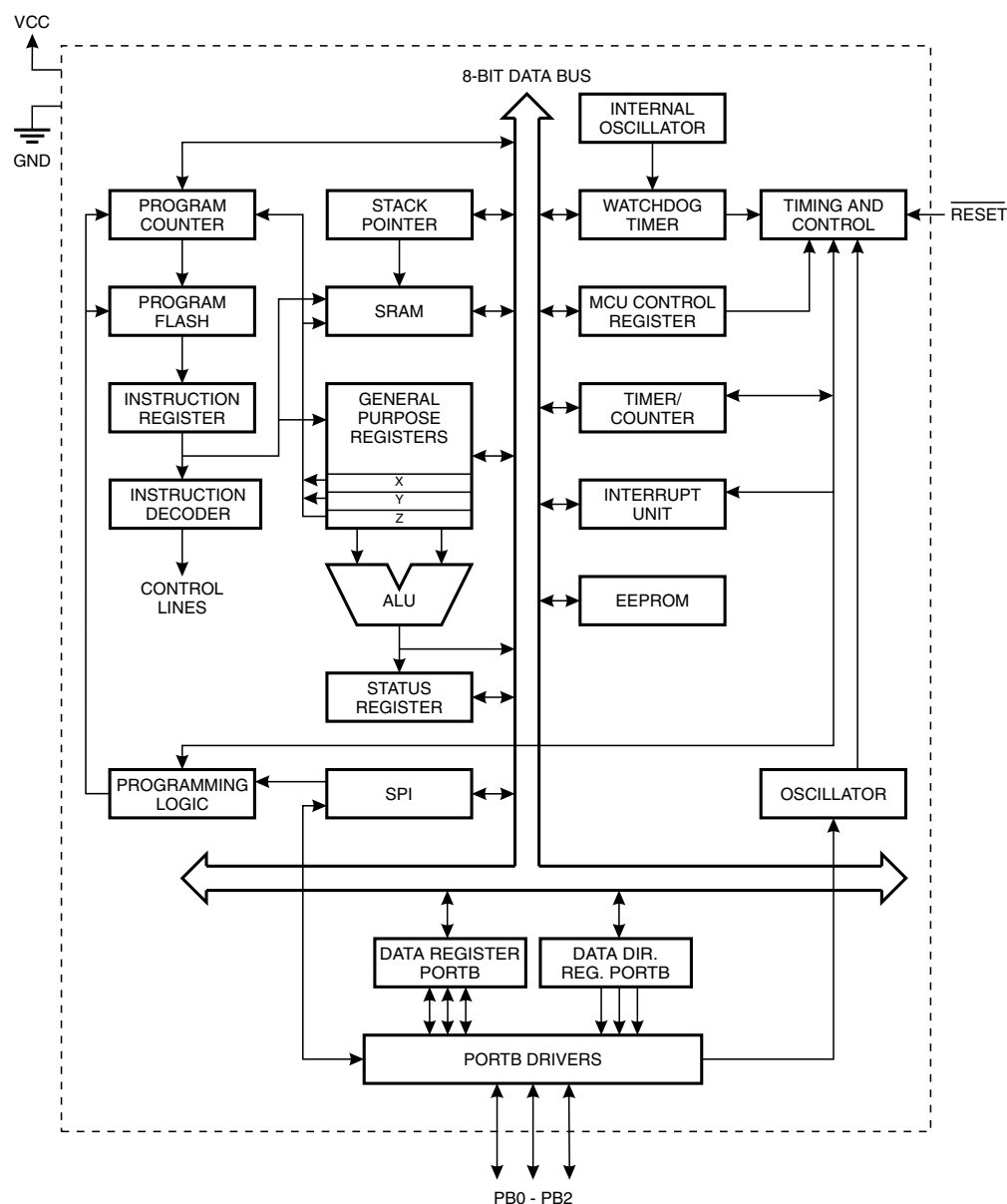
"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

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Details

Product Status	Obsolete
Core Processor	AVR
Core Size	8-Bit
Speed	10MHz
Connectivity	SPI
Peripherals	Brown-out Detect/Reset, POR, WDT
Number of I/O	3
Program Memory Size	2KB (1K x 16)
Program Memory Type	FLASH
EEPROM Size	128 x 8
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	4V ~ 6V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.209", 5.30mm Width)
Supplier Device Package	8-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/at90s2323-10si

Figure 2. The AT90S/LS2323 Block Diagram



The AT90S2323/2343 provides the following features: 2K bytes of In-System Programmable Flash, 128 bytes EEPROM, 128 bytes SRAM, 3 (AT90S/LS2323)/5 (AT90S/LS2343) general-purpose I/O lines, 32 general-purpose working registers, an 8-bit timer/counter, internal and external interrupts, programmable Watchdog Timer with internal oscillator, an SPI serial port for Flash Memory downloading and two software-selectable power-saving modes. The Idle mode stops the CPU while allowing the SRAM, timer/counters, SPI port and interrupt system to continue functioning. The Power-down mode saves the register contents but freezes the oscillator, disabling all other chip functions until the next interrupt or hardware reset.

The device is manufactured using Atmel's high-density nonvolatile memory technology. The On-chip Flash allows the program memory to be reprogrammed in-system through an SPI serial interface. By combining an 8-bit RISC CPU with ISP Flash on a monolithic

The AVR has Harvard architecture – with separate memories and buses for program and data. The program memory is accessed with a two-stage pipeline. While one instruction is being executed, the next instruction is pre-fetched from the program memory. This concept enables instructions to be executed in every clock cycle. The program memory is in-system downloadable Flash memory.

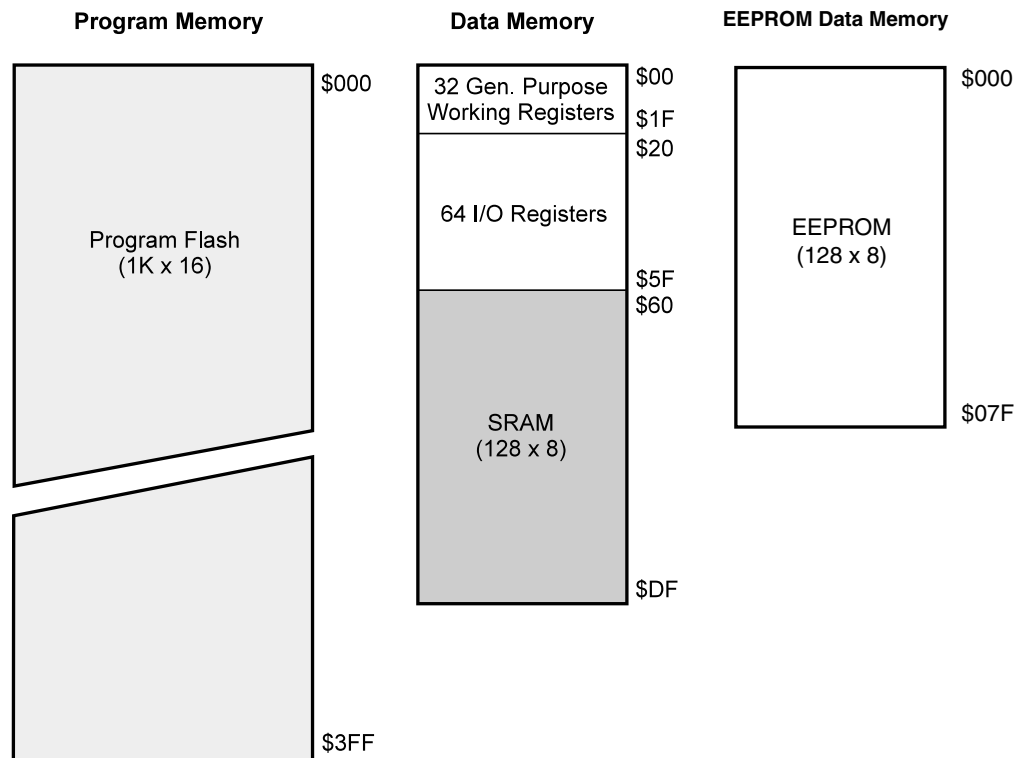
With the relative jump and call instructions, the whole 1K address space is directly accessed. Most AVR instructions have a single 16-bit word format. Every program memory address contains a 16- or 32-bit instruction.

During interrupts and subroutine calls, the return address Program Counter (PC) is stored on the stack. The stack is effectively allocated in the general data SRAM and consequently, the stack size is only limited by the total SRAM size and the usage of the SRAM. All user programs must initialize the SP in the reset routine (before subroutines or interrupts are executed). The 8-bit stack pointer (SP) is read/write-accessible in the I/O space.

The 128 bytes data SRAM + register file and I/O registers can be easily accessed through the five different addressing modes supported in the AVR architecture.

The memory spaces in the AVR architecture are all linear and regular memory maps.

Figure 6. Memory Maps

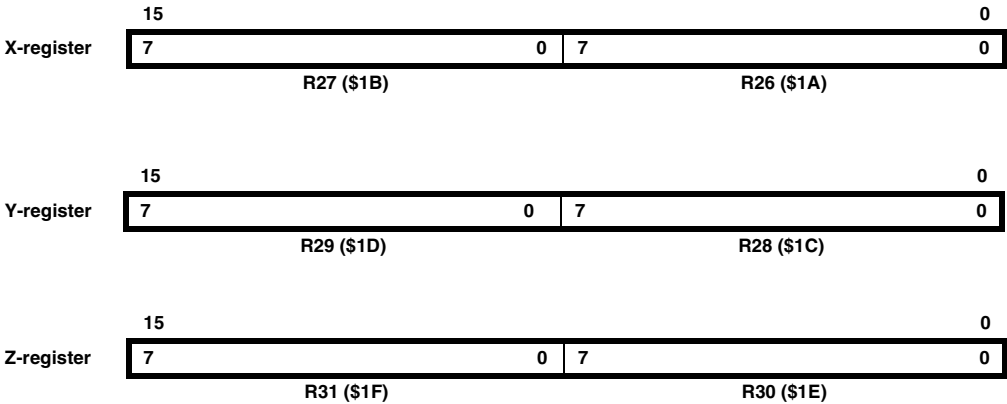


A flexible interrupt module has its control registers in the I/O space with an additional global interrupt enable bit in the status register. All the different interrupts have a separate interrupt vector in the interrupt vector table at the beginning of the program memory. The different interrupts have priority in accordance with their interrupt vector position. The lower the interrupt vector address, the higher the priority.

X-register, Y-register and Z-register

The registers R26..R31 have some added functions to their general-purpose usage. These registers are the address pointers for indirect addressing of the Data Space. The three indirect address registers X, Y, and Z, are defined in Figure 8.

Figure 8. The X-, Y-, and Z-registers



In the different addressing modes, these address registers have functions as fixed displacement, automatic increment and decrement (see the descriptions for the different instructions).

ALU – Arithmetic Logic Unit

The high-performance AVR ALU operates in direct connection with all the 32 general-purpose working registers. Within a single clock cycle, ALU operations between registers in the register file are executed. The ALU operations are divided into three main categories: arithmetic, logic and bit functions.

In-System Programmable Flash Program Memory

The AT90S2323/2343 contains 2K bytes On-chip, In-System Programmable Flash memory for program storage. Since all instructions are 16- or 32-bit words, the Flash is organized as 1K x 16. The Flash memory has an endurance of at least 1000 write/erase cycles.

The AT90S2323/2343 Program Counter (PC) is 10 bits wide, hence addressing the 1024 program memory addresses. See page 42 for a detailed description on Flash data programming.

Constant tables must be allocated within the address 0 - 2K (see the LPM – Load Program Memory instruction description on page 60).

See page 12 for the different addressing modes.

EEPROM Data Memory

The AT90S2323/2343 contains 128 bytes of EEPROM data memory. It is organized as a separate data space, in which single bytes can be read and written. The EEPROM has an endurance of at least 100,000 write/erase cycles. The access between the EEPROM and the CPU is described on page 32, specifying the EEPROM address register, the EEPROM data register and the EEPROM control register.

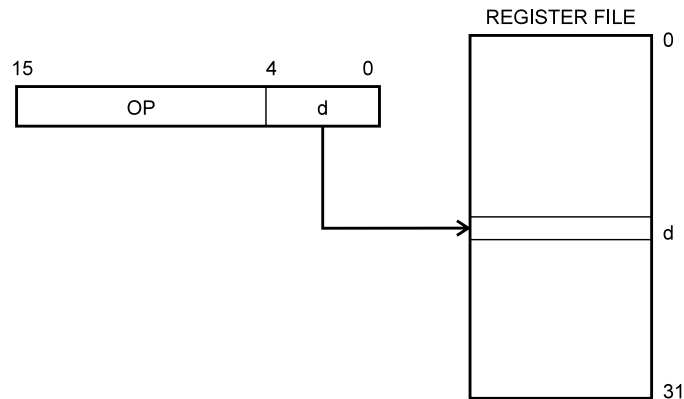
For the SPI data downloading, see page 42 for a detailed description.

Program and Data Addressing Modes

The AT90S2323/2343 AVR RISC microcontroller supports powerful and efficient addressing modes for access to the program memory (Flash) and data memory. This section describes the different addressing modes supported by the AVR architecture. In the figures, OP means the operation code part of the instruction word. To simplify, not all figures show the exact location of the addressing bits.

Register Direct, Single Register Rd

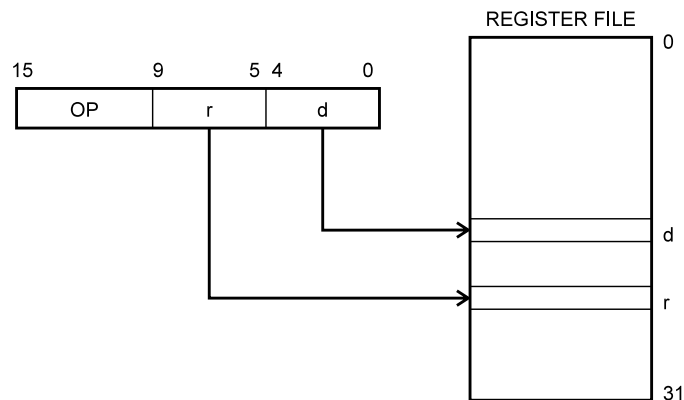
Figure 10. Direct Single Register Addressing



The operand is contained in register d (Rd).

Register Direct, Two Registers Rd and Rr

Figure 11. Direct Register Addressing, Two Registers



Operands are contained in register r (Rr) and d (Rd). The result is stored in register d (Rd).

• Bit 0 – C: Carry Flag

The carry flag C indicates a carry in an arithmetical or logical operation. See the Instruction Set description for detailed information.

Note that the Status Register is not automatically stored when entering an interrupt routine and restored when returning from an interrupt routine. This must be handled by software.

Stack Pointer – SPL

An 8-bit register at I/O address \$3D (\$5D) forms the stack pointer of the AT90S2323/2343. Eight bits are used to address the 128 bytes of SRAM in locations \$60 - \$DF.

Bit	7	6	5	4	3	2	1	0	
\$3D (\$5D)	SP7	SP6	SP5	SP4	SP3	SP2	SP1	SP0	SPL
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

The Stack Pointer points to the data SRAM stack area where the Subroutine and Interrupt stacks are located. This stack space in the data SRAM must be defined by the program before any subroutine calls are executed or interrupts are enabled. The Stack Pointer must be set to point above \$60. The Stack Pointer is decremented by 1 when data is pushed onto the Stack with the PUSH instruction and it is decremented by 2 when an address is pushed onto the stack with subroutine calls and interrupts. The Stack Pointer is incremented by 1 when data is popped from the stack with the POP instruction and it is incremented by 2 when an address is popped from the stack with return from subroutine RET or return from interrupt RETI.

Reset and Interrupt Handling

The AT90S2323/2343 provides two interrupt sources. These interrupts and the separate reset vector each have a separate program vector in the program memory space. Both interrupts are assigned individual enable bits that must be set (one) together with the I-bit in the Status Register in order to enable the interrupt.

The lowest addresses in the program memory space are automatically defined as the Reset and Interrupt vectors. The complete list of vectors is shown in Table 3. The list also determines the priority levels of the interrupts. The lower the address, the higher the priority level. RESET has the highest priority, and next is INT0 (the External Interrupt Request 0), etc.

Table 3. Reset and Interrupt Vectors

Vector No.	Program Address	Source	Interrupt Definition
1	\$000	RESET	Hardware Pin, Power-on Reset and Watchdog Reset
2	\$001	INT0	External Interrupt Request 0
3	\$002	TIMER0, OVFO	Timer/Counter0 Overflow

Table 4. Reset Characteristics ($V_{CC} = 5.0V$)

Symbol	Parameter	Min	Typ	Max	Units
$V_{POT}^{(1)}$	Power-on Reset Threshold Voltage, rising	1.0	1.4	1.8	V
	Power-on Reset Threshold Voltage, falling	0.4	0.6	0.8	V
V_{RST}	\overline{RESET} Pin Threshold Voltage		$0.6 V_{CC}$		V
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2323 FSTRT Programmed	1.0	1.1	1.2	ms
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2323 FSTRT Unprogrammed	11.0	16.0	21.0	ms
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2343	11.0	16.0	21.0	μs

Note: 1. The Power-on Reset will not work unless the supply voltage has been below V_{POT} (falling).

Table 5. Reset Characteristics ($V_{CC} = 3.0V$)

Symbol	Parameter	Min	Typ	Max	Units
$V_{POT}^{(1)}$	Power-on Reset Threshold Voltage, rising	1.0	1.4	1.8	V
	Power-on Reset Threshold Voltage, falling	0.4	0.6	0.8	V
V_{RST}	\overline{RESET} Pin Threshold Voltage		$0.6 V_{CC}$		V
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2323 FSTRT Programmed	2.0	2.2	2.4	ms
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2323 FSTRT Unprogrammed	22.0	32.0	42.0	ms
t_{TOUT}	Reset Delay Time-out Period AT90S/LS2343	22.0	32.0	42.0	μs

Note: 1. The Power-on Reset will not work unless the supply voltage has been below V_{POT} (falling).

Power-on Reset

The AT90S2323/2343 is designed for use in systems where it can operate from the internal RC oscillator (AT90S/LS2343), on-chip oscillator (AT90S/LS2323), or in applications where a clock signal is provided by an external clock source. After V_{CC} has reached V_{POT} , the device will start after the time t_{TOUT} (see Figure 25). If the clock signal is provided by an external clock source, the clock must not be applied until V_{CC} has reached the minimum voltage defined for the applied frequency.

For AT90S2323, the user can select the start-up time according to typical oscillator start-up. The number of WDT oscillator cycles used for each time-out is shown in Table 6. For AT90S2343, the start-up time is one Watchdog cycle only. The frequency of the Watchdog oscillator is voltage-dependent as shown in "Typical Characteristics" on page 49.

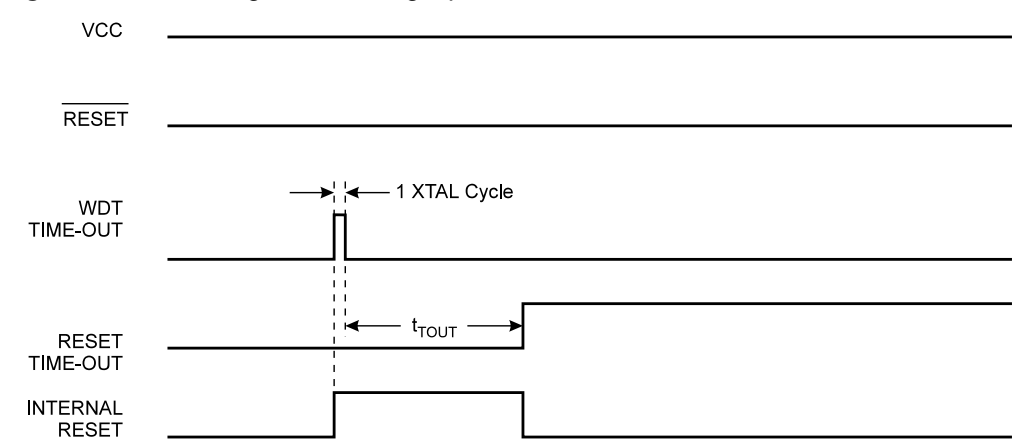
Table 6. Number of Watchdog Oscillator Cycles

FSTRT	Time-out at $V_{CC} = 5V$	Number of WDT Cycles
Programmed	1.1 ms	1K
Unprogrammed	16.0 ms	16K

Watchdog Reset

When the Watchdog times out, it will generate a short reset pulse of 1 CPU clock cycle duration. On the falling edge of this pulse, the delay timer starts counting the Time-out period t_{TOUT} . Refer to page 30 for details on operation of the Watchdog.

Figure 28. Watchdog Reset during Operation



MCU Status Register – MCUSR

The MCU Status Register provides information on which reset source caused an MCU reset.

Bit	7	6	5	4	3	2	1	0	
\$34 (\$54)	–	–	–	–	–	–	EXTRF	PORF	MCUSR
Read/Write	R	R	R	R	R	R	R/W	R/W	
Initial Value	0	0	0	0	0	0	See Bit Description		

• Bits 7..2 – Res: Reserved Bits

These bits are reserved bits in the AT90S2323/2343 and always read as zero.

• Bit 1 – EXTRF: External Reset Flag

After a Power-on Reset, this bit is undefined (X). It will be set by an External Reset. A Watchdog Reset will leave this bit unchanged.

• Bit 0 – PORF: Power-on Reset Flag

This bit is set by a Power-on Reset. A Watchdog Reset or an External Reset will leave this bit unchanged.

To summarize, Table 7 shows the value of these two bits after the three modes of reset.

Table 7. PORF and EXTRF Values after Reset

Reset Source	PORF	EXTRF
Power-on Reset	1	Undefined
External Reset	Unchanged	1
Watchdog Reset	Unchanged	Unchanged

To make use of these bits to identify a reset condition, the user software should clear both the PORF and EXTRF bits as early as possible in the program. Checking the PORF and EXTRF values is done before the bits are cleared. If the bit is cleared before an External or Watchdog Reset occurs, the source of reset can be found by using the following truth table, Table 8.

General Interrupt Flag Register – GIFR

Bit	7	6	5	4	3	2	1	0	
\$3A (\$5A)	–	INTF0	–	–	–	–	–	–	GIFR
Read/Write	R	R/W	R	R	R	R	R	R	
Initial Value	0	0	0	0	0	0	0	0	

- **Bit 7 – Res: Reserved Bit**

This bit is a reserved bit in the AT90S2323/2343 and always reads as zero.

- **Bit 6 – INTF0: External Interrupt Flag0**

When an edge on the INT0 pin triggers an interrupt request, the corresponding interrupt flag, INTF0 becomes set (one). If the I-bit in SREG and the corresponding interrupt enable bit, INT0 in GIMSK, is set (one), the MCU will jump to the interrupt vector. The flag is cleared when the interrupt routine is executed. Alternatively, the flag is cleared by writing a logical “1” to it. This flag is always cleared when INT0 is configured as level interrupt.

- **Bits 5..0 – Res: Reserved Bits**

These bits are reserved bits in the AT90S2323/2343 and always read as zero.

Timer/Counter Interrupt Mask Register – TIMSK

Bit	7	6	5	4	3	2	1	0	
\$39 (\$59)	–	–	–	–	–	–	TOIE0	–	TIMSK
Read/Write	R	R	R	R	R	R	R/W	R	
Initial Value	0	0	0	0	0	0	0	0	

- **Bits 7..2 – Res: Reserved Bits**

These bits are reserved bits in the AT90S2323/2343 and always read zero.

- **Bit 1 – TOIE0: Timer/Counter0 Overflow Interrupt Enable**

When the TOIE0 bit is set (one) and the I-bit in the Status Register is set (one), the Timer/Counter0 Overflow interrupt is enabled. The corresponding interrupt (at vector \$002) is executed if an overflow in Timer/Counter0 occurs, i.e., when the Overflow Flag (Timer/Counter0) is set (one) in the Timer/Counter Interrupt Flag Register (TIFR).

- **Bit 0 – Res: Reserved Bit**

This bit is a reserved bit in the AT90S2323/2343 and always reads as zero.

Timer/Counter Interrupt FLAG Register – TIFR

Bit	7	6	5	4	3	2	1	0	
\$38 (\$58)	–	–	–	–	–	–	TOV0	–	TIFR
Read/Write	R	R	R	R	R	R	R/W	R	
Initial Value	0	0	0	0	0	0	0	0	

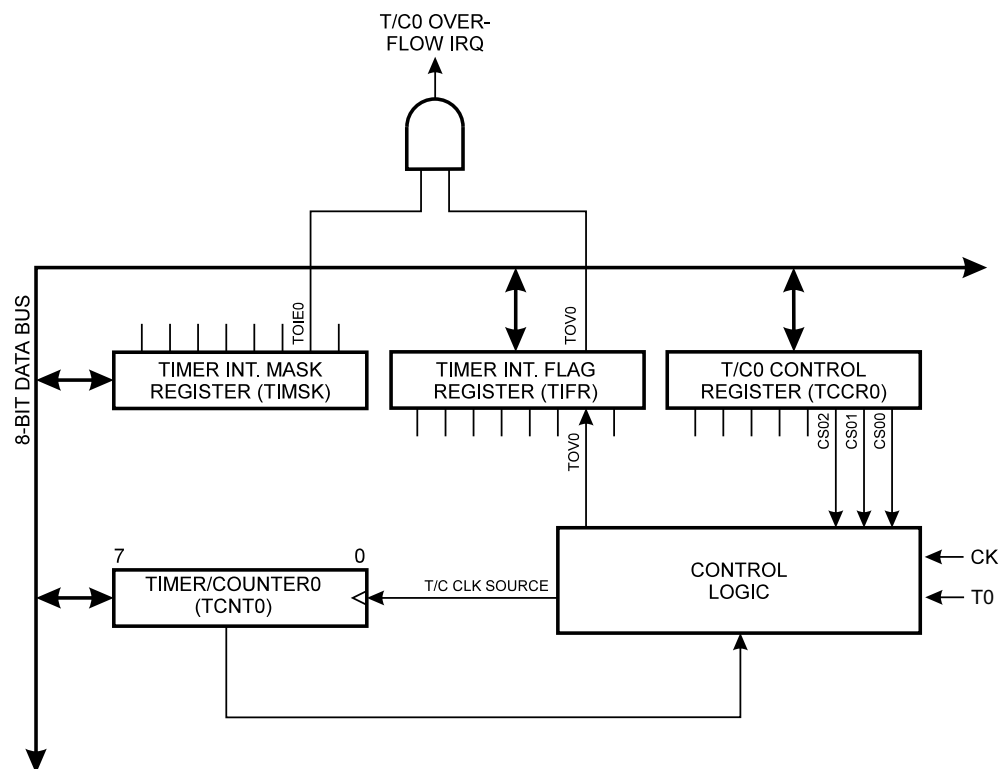
- **Bits 7..2 – Res: Reserved Bits**

These bits are reserved bits in the AT90S2323/2343 and always read zero.

- **Bit 1 – TOV0: Timer/Counter0 Overflow Flag**

The bit TOV0 is set (one) when an overflow occurs in Timer/Counter0. TOV0 is cleared by hardware when executing the corresponding interrupt handling vector. Alternatively, TOV0 is cleared by writing a logical “1” to the flag. When the SREG I-bit and TOIE0 (Timer/Counter0 Overflow Interrupt Enable) and TOV0 are set (one), the Timer/Counter0 Overflow Interrupt is executed.

Figure 30. Timer/Counter 0 Block Diagram



Timer/Counter0 Control Register – TCCR0

Bit	7	6	5	4	3	2	1	0	
\$33 (\$53)	–	–	–	–	–	CS02	CS01	CS00	TCCR0
Read/Write	R	R	R	R	R	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

- Bits 7..3 – Res: Reserved Bits**

These bits are reserved bits in the AT90S2323/2343 and always read zero.

- Bits 2, 1, 0 – CS02, CS01, CS00: Clock Select0, Bits 2, 1 and 0**

The Clock Select0 bits 2, 1 and 0 define the prescaling source of Timer/Counter0.

Table 10. Clock 0 Prescale Select

CS02	CS01	CS00	Description
0	0	0	Stop, the Timer/Counter0 is stopped.
0	0	1	CK
0	1	0	CK/8
0	1	1	CK/64
1	0	0	CK/256
1	0	1	CK/1024
1	1	0	External Pin T0, falling edge
1	1	1	External Pin T0, rising edge

The Stop condition provides a Timer Enable/Disable function. The CK down divided modes are scaled directly from the CK oscillator clock. If the external pin modes are used for Timer/Counter0, transitions on PB2/(T0) will clock the counter even if the pin is configured as an output. This feature can give the user software control of the counting.

Timer/Counter0 – TCNT0

Bit	7	6	5	4	3	2	1	0	
\$32 (\$52)	MSB							LSB	TCNT0
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

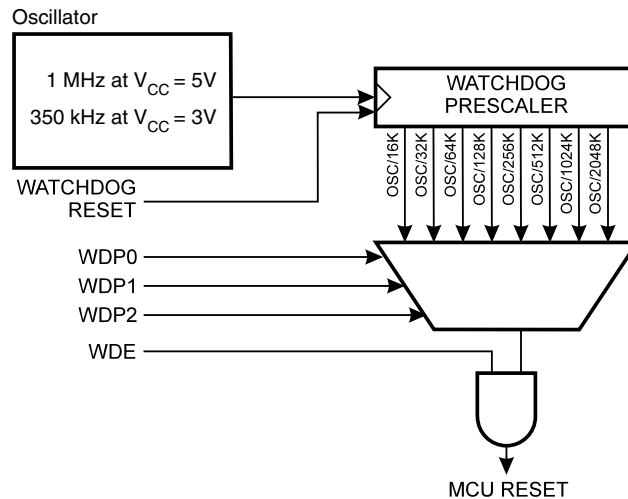
The Timer/Counter0 is realized as an up-counter with read and write access. If the Timer/Counter0 is written and a clock source is present, the Timer/Counter0 continues counting in the timer clock cycle following the write operation.

Watchdog Timer

The Watchdog Timer is clocked from a separate On-chip oscillator. By controlling the Watchdog Timer prescaler, the Watchdog reset interval can be adjusted as shown in Table 11. See characterization data for typical values at other V_{CC} levels. The WDR (Watchdog Reset) instruction resets the Watchdog Timer. Eight different clock cycle periods can be selected to determine the reset period. If the reset period expires without another Watchdog reset, the AT90S2323/2343 resets and executes from the reset vector. For timing details on the Watchdog reset, refer to page 23.

To prevent unintentional disabling of the Watchdog, a special turn-off sequence must be followed when the Watchdog is disabled. Refer to the description of the Watchdog Timer Control Register for details.

Figure 31. Watchdog Timer



EEPROM Read/Write Access

The EEPROM access registers are accessible in the I/O space.

The write access time is in the range of 2.5 - 4 ms, depending on the V_{CC} voltages. A self-timing function, however, lets the user software detect when the next byte can be written.

In order to prevent unintentional EEPROM writes, a specific write procedure must be followed. Refer to the description of the EEPROM Control Register for details on this.

When the EEPROM is written, the CPU is halted for two clock cycles before the next instruction is executed. When the EEPROM is read, the CPU is halted for four clock cycles before the next instruction is executed.

EEPROM Address Register – EEAR

Bit	7	6	5	4	3	2	1	0	
\$1E (\$3E)	–	EEAR6	EEAR5	EEAR4	EEAR3	EEAR2	EEAR1	EEAR0	EEAR
Read/Write	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

- **Bit 7 – Res: Reserved Bit**

This bit is a reserved bit in the AT90S2323/2343 and will always read as zero.

- **Bit 6..0 – EEAR6..0: EEPROM Address**

The EEPROM Address Register (EEAR6..0) specifies the EEPROM address in the 128-byte EEPROM space. The EEPROM data bytes are addressed linearly between 0 and 127.

EEPROM Data Register – EEDR

Bit	7	6	5	4	3	2	1	0	
\$1D (\$3D)	MSB							LSB	EEDR
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

- **Bits 7..0 – EEDR7..0: EEPROM Data**

For the EEPROM write operation, the EEDR register contains the data to be written to the EEPROM in the address given by the EEAR register. For the EEPROM read operation, the EEDR contains the data read out from the EEPROM at the address given by EEAR.

Prevent EEPROM Corruption

During periods of low V_{CC} , the EEPROM data can be corrupted because the supply voltage is too low for the CPU and the EEPROM to operate properly. These issues are the same as for board level systems using the EEPROM and the same design solutions should be applied.

An EEPROM data corruption can be caused by two situations when the voltage is too low. First, a regular write sequence to the EEPROM requires a minimum voltage to operate correctly. Secondly, the CPU itself can execute instructions incorrectly, if the supply voltage for executing instructions is too low.

EEPROM data corruption can easily be avoided by following these design recommendations (one is sufficient):

1. Keep the AVR RESET active (low) during periods of insufficient power supply voltage. This is best done by an external low V_{CC} Reset Protection circuit, often referred to as a Brown-out Detector (BOD). Please refer to application note AVR 180 for design considerations regarding power-on reset and low-voltage detection.
2. Keep the AVR core in Power-down Sleep mode during periods of low V_{CC} . This will prevent the CPU from attempting to decode and execute instructions, effectively protecting the EEPROM registers from unintentional writes.
3. Store constants in Flash memory if the ability to change memory contents from software is not required. Flash memory cannot be updated by the CPU and will not be subject to corruption.



3. \$002: \$03 (indicates AT90S/LS2343 when signature byte \$001 is \$91)

Note: When both Lock bits are programmed (Lock mode 3), the signature bytes cannot be read in the low-voltage Serial mode. Reading the signature bytes will return: \$00, \$01 and \$02.

Programming the Flash and EEPROM

Atmel's AT90S2323/2343 offers 2K bytes of In-System Programmable Flash program memory and 128 bytes of EEPROM data memory.

The AT90S2323/2343 is shipped with the On-chip Flash program and EEPROM data memory arrays in the erased state (i.e., contents = \$FF) and ready to be programmed.

The device supports a high-voltage (12V) Serial Programming mode and a low-voltage Serial Programming mode. The +12V is used for programming enable only and no current of significance is drawn by this pin. The low-voltage Serial Programming mode provides a convenient way to download program and data into the device inside the user's system.

The program and EEPROM memory arrays in the AT90S2323/2343 are programmed byte-by-byte in either programming modes. For the EEPROM, an auto-erase cycle is provided within the self-timed write instruction in the low-voltage Serial Programming mode.

During programming, the supply voltage must be in accordance with Table 15.

Table 15. Supply Voltage during Programming

Part	Low-voltage Serial Programming	High-voltage Serial Programming
AT90S2323	4.0 - 6.0V	4.5 - 5.5V
AT90LS2323	2.7 - 6.0V	4.5 - 5.5V
AT90S2323	4.0 - 6.0V	4.5 - 5.5V
AT90LS2323	2.7 - 6.0V	4.5 - 5.5V

High-voltage Serial Programming

This section describes how to program and verify Flash program memory, EEPROM data memory, Lock bits and Fuse bits in the AT90S2323/2343.

Figure 32. High-voltage Serial Programming

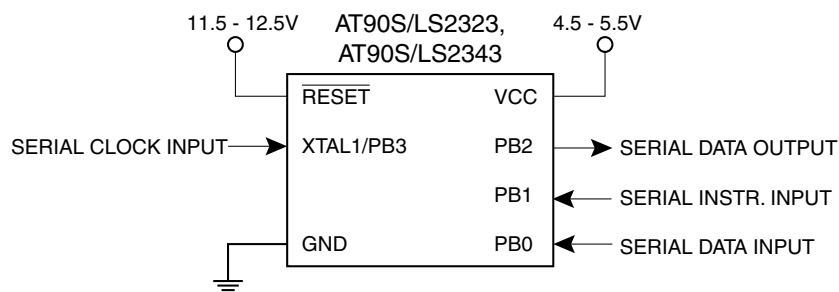


Table 16. High-voltage Serial Programming Instruction Set (Continued)

Instruction		Instruction Format				Operation Remarks
		Instr.1	Instr.2	Instr.3	Instr.4	
Read Fuse and Lock Bits (AT90S/LS2323)	PB0	0_0000_0100_00	0_0000_0000_00	0_0000_0000_00		Reading 1 , 2 , S , R = "0" means the Fuse/Lock bit is programmed.
	PB1	0_0100_1100_00	0_0111_1000_00	0_0111_1100_00		
	PB2	x_xxxx_xxxx_xx	x_xxxx_xxxx_xx	1_2S xx_xx R x_xx		
Read Fuse and Lock Bits (AT90S/LS2343)	PB0	0_0000_0100_00	0_0000_0000_00	0_0000_0000_00		Reading 1 , 2 , S , R = "0" means the Fuse/Lock bit is programmed.
	PB1	0_0100_1100_00	0_0111_1000_00	0_0111_1100_00		
	PB2	x_xxxx_xxxx_xx	x_xxxx_xxxx_xx	1_2S xx_xx R x_xx		
Read Signature Bytes	PB0	0_0000_1000_00	0_0000_00 bb _00	0_0000_0000_00	0_0000_0000_00	Repeat Instr.2 - Instr.4 for each signature byte address.
	PB1	0_0100_1100_00	0_0000_1100_00	0_0110_1000_00	0_0110_1100_00	
	PB2	x_xxxx_xxxx_xx	x_xxxx_xxxx_xx	x_xxxx_xxxx_xx	o_oooo_ooo x_xx	

Note: **a** = address high bits
b = address low bits
i = data in
o = data out
x = don't care
1 = Lock Bit1
2 = Lock Bit2
F = FSTRT Fuse
R = RCEN Fuse
S = SPIEN Fuse

For the EEPROM, an auto-erase cycle is provided within the self-timed Write instruction and there is no need to first execute the Chip Erase instruction. The Chip Erase instruction turns the content of every memory location in both the program and EEPROM arrays into \$FF.

The program and EEPROM memory arrays have separate address spaces: \$0000 to \$03FF for Flash program memory and \$000 to \$07F for EEPROM data memory.

Either an external clock is applied to the XTAL1/PB3 pin or the device must be clocked from the internal RC oscillator (AT90S/LS2343 only). The minimum low and high periods for the serial clock (SCK) input are defined as follows:

Low: > 2 MCU clock cycles

High: > 2 MCU clock cycles

Low-voltage Serial Programming Algorithm

When writing serial data to the AT90S2323/2343, data is clocked on the rising edge of SCK.

When reading data from the AT90S2323/2343, data is clocked on the falling edge of SCK. See Figure 36, Figure 37 and Table 20 for timing details.

To program and verify the AT90S2323/2343 in the low-voltage Serial Programming mode, the following sequence is recommended (see 4-byte instruction formats in Table 19):

1. Power-up sequence:

Apply power between V_{CC} and GND while RESET and SCK are set to "0". (If the programmer cannot guarantee that SCK is held low during power-up, RESET must be given a positive pulse after SCK has been set to "0".) If the device is programmed for external clocking, apply a 0 - 8 MHz clock to the XTAL1/PB3 pin. If the internal RC oscillator is selected as the clock source, no external clock source needs to be applied (AT90S/LS2343 only).

2. Wait for at least 20 ms and enable serial programming by sending the Programming Enable serial instruction to the MOSI (PB0) pin. Refer to the above section for minimum low and high periods for the serial clock input, SCK.
3. The serial programming instructions will not work if the communication is out of synchronization. When in sync, the second byte (\$53) will echo back when issuing the third byte of the Programming Enable instruction. Whether the echo is correct or not, all four bytes of the instruction must be transmitted. If the \$53 did not echo back, give SCK a positive pulse and issue a new Programming Enable instruction. If the \$53 is not seen within 32 attempts, there is no functional device connected.
4. If a Chip Erase is performed (must be done to erase the Flash), wait t_{WD_ERASE} after the instruction, give \overline{RESET} a positive pulse and start over from step 2. See Table 21 on page 46 for t_{WD_ERASE} value.
5. The Flash or EEPROM array is programmed one byte at a time by supplying the address and data together with the appropriate Write instruction. An EEPROM memory location is first automatically erased before new data is written. Use Data Polling to detect when the next byte in the Flash or EEPROM can be written. If polling is not used, wait t_{WD_PROG} before transmitting the next instruction. See Table 22 on page 46 for t_{WD_PROG} value. In an erased device, no \$FFs in the data file(s) need to be programmed.
6. Any memory location can be verified by using the Read instruction, which returns the content at the selected address at the serial output MISO (PB1) pin.

Low-voltage Serial Programming Characteristics

Figure 37. Low-voltage Serial Programming Timing

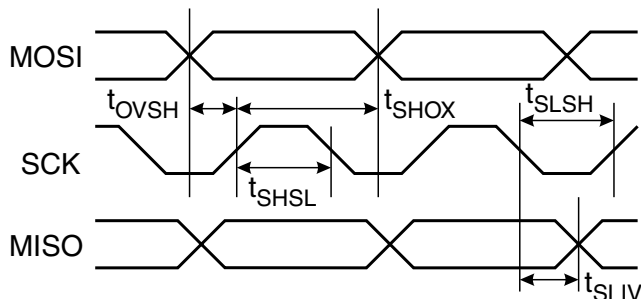


Table 20. Low-voltage Serial Programming Characteristics, $T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 2.7 - 6.0\text{V}$ (unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Units
$1/t_{CLCL}$	Oscillator Frequency ($V_{CC} = 2.7 - 4.0\text{V}$)	0		4.0	MHz
t_{CLCL}	Oscillator Period ($V_{CC} = 2.7 - 4.0\text{V}$)	250.0			ns
$1/t_{CLCL}$	Oscillator Frequency ($V_{CC} = 4.0 - 6.0\text{V}$)	0		8.0	MHz
t_{CLCL}	Oscillator Period ($V_{CC} = 4.0 - 6.0\text{V}$)	125.0			ns
t_{SHSL}	SCK Pulse Width High	$2.0 t_{CLCL}$			ns
t_{SLSH}	SCK Pulse Width Low	$2.0 t_{CLCL}$			ns
t_{OVSH}	MOSI Setup to SCK High	t_{CLCL}			ns
t_{SHOX}	MOSI Hold after SCK High	$2.0 t_{CLCL}$			ns
t_{SLIV}	SCK Low to MISO Valid	10.0	16.0	32.0	ns

Table 21. Minimum Wait Delay after the Chip Erase Instruction

Symbol	3.2V	3.6V	4.0V	5.0V
t_{WD_ERASE}	18 ms	14 ms	12 ms	8 ms

Table 22. Minimum Wait Delay after Writing a Flash or EEPROM Location

Symbol	3.2V	3.6V	4.0V	5.0V
t_{WD_PROG}	9 ms	7 ms	6 ms	4 ms

Figure 44. Idle Supply Current vs. V_{CC}

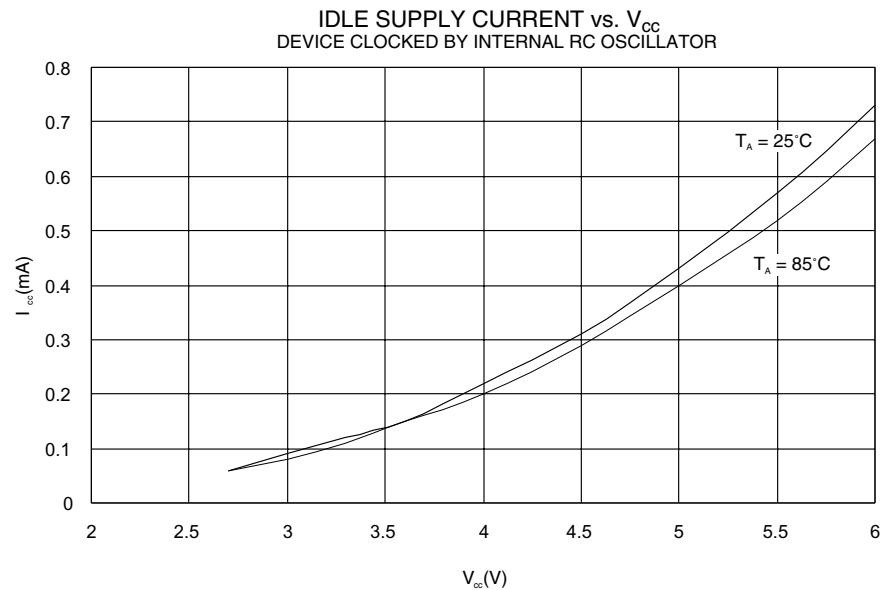


Figure 45. Power-down Supply Current vs. V_{CC}

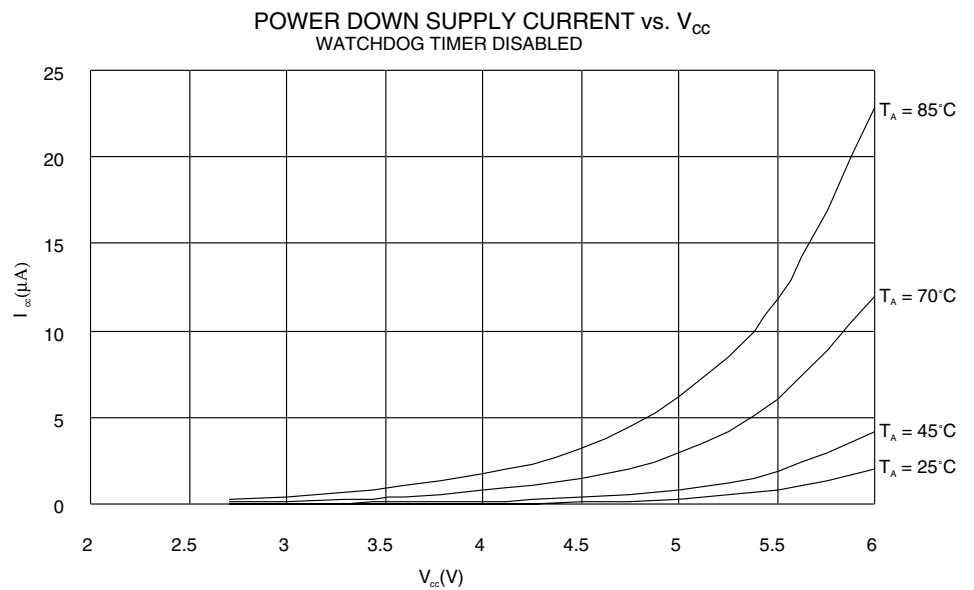


Figure 46. Power-down Supply Current vs. V_{CC}

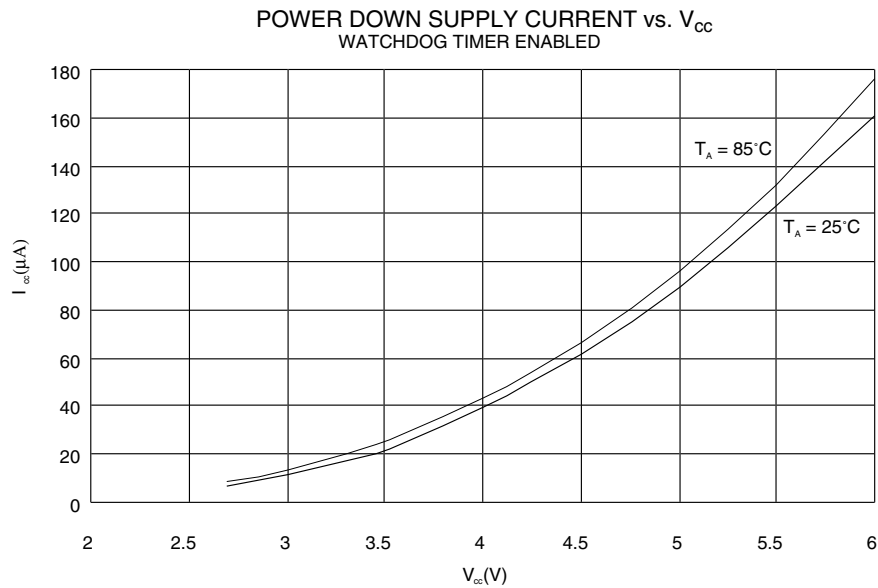
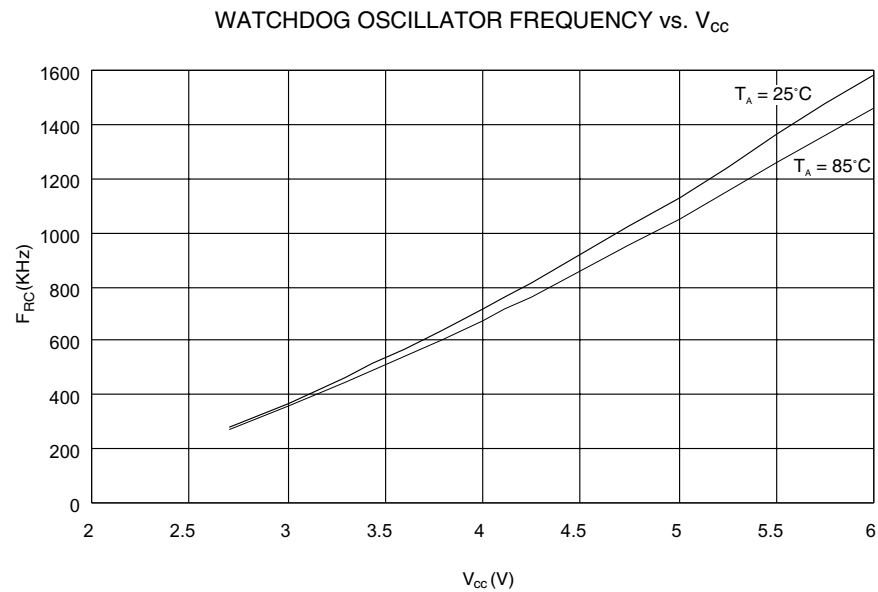


Figure 47. Watchdog Oscillator Frequency vs. V_{CC}



Instruction Set Summary (Continued)

Mnemonic	Operands	Description	Operation	Flags	# Clocks
DATA TRANSFER INSTRUCTIONS					
MOV	Rd, Rr	Move between Registers	$Rd \leftarrow Rr$	None	1
LDI	Rd, K	Load Immediate	$Rd \leftarrow K$	None	1
LD	Rd, X	Load Indirect	$Rd \leftarrow (X)$	None	2
LD	Rd, X+	Load Indirect and Post-inc.	$Rd \leftarrow (X), X \leftarrow X + 1$	None	2
LD	Rd, -X	Load Indirect and Pre-dec.	$X \leftarrow X - 1, Rd \leftarrow (X)$	None	2
LD	Rd, Y	Load Indirect	$Rd \leftarrow (Y)$	None	2
LD	Rd, Y+	Load Indirect and Post-inc.	$Rd \leftarrow (Y), Y \leftarrow Y + 1$	None	2
LD	Rd, -Y	Load Indirect and Pre-dec.	$Y \leftarrow Y - 1, Rd \leftarrow (Y)$	None	2
LDD	Rd, Y+q	Load Indirect with Displacement	$Rd \leftarrow (Y + q)$	None	2
LD	Rd, Z	Load Indirect	$Rd \leftarrow (Z)$	None	2
LD	Rd, Z+	Load Indirect and Post-inc.	$Rd \leftarrow (Z), Z \leftarrow Z + 1$	None	2
LD	Rd, -Z	Load Indirect and Pre-dec.	$Z \leftarrow Z - 1, Rd \leftarrow (Z)$	None	2
LDD	Rd, Z+q	Load Indirect with Displacement	$Rd \leftarrow (Z + q)$	None	2
LDS	Rd, k	Load Direct from SRAM	$Rd \leftarrow (k)$	None	2
ST	X, Rr	Store Indirect	$(X) \leftarrow Rr$	None	2
ST	X+, Rr	Store Indirect and Post-inc.	$(X) \leftarrow Rr, X \leftarrow X + 1$	None	2
ST	-X, Rr	Store Indirect and Pre-dec.	$X \leftarrow X - 1, (X) \leftarrow Rr$	None	2
ST	Y, Rr	Store Indirect	$(Y) \leftarrow Rr$	None	2
ST	Y+, Rr	Store Indirect and Post-inc.	$(Y) \leftarrow Rr, Y \leftarrow Y + 1$	None	2
ST	-Y, Rr	Store Indirect and Pre-dec.	$Y \leftarrow Y - 1, (Y) \leftarrow Rr$	None	2
STD	Y+q, Rr	Store Indirect with Displacement	$(Y + q) \leftarrow Rr$	None	2
ST	Z, Rr	Store Indirect	$(Z) \leftarrow Rr$	None	2
ST	Z+, Rr	Store Indirect and Post-inc.	$(Z) \leftarrow Rr, Z \leftarrow Z + 1$	None	2
ST	-Z, Rr	Store Indirect and Pre-dec.	$Z \leftarrow Z - 1, (Z) \leftarrow Rr$	None	2
STD	Z+q, Rr	Store Indirect with Displacement	$(Z + q) \leftarrow Rr$	None	2
STS	k, Rr	Store Direct to SRAM	$(k) \leftarrow Rr$	None	2
LPM		Load Program Memory	$R0 \leftarrow (Z)$	None	3
IN	Rd, P	In Port	$Rd \leftarrow P$	None	1
OUT	P, Rr	Out Port	$P \leftarrow Rr$	None	1
PUSH	Rr	Push Register on Stack	$STACK \leftarrow Rr$	None	2
POP	Rd	Pop Register from Stack	$Rd \leftarrow STACK$	None	2
BIT AND BIT-TEST INSTRUCTIONS					
SBI	P, b	Set Bit in I/O Register	$I/O(P,b) \leftarrow 1$	None	2
CBI	P, b	Clear Bit in I/O Register	$I/O(P,b) \leftarrow 0$	None	2
LSL	Rd	Logical Shift Left	$Rd(n+1) \leftarrow Rd(n), Rd(0) \leftarrow 0$	Z,C,N,V	1
LSR	Rd	Logical Shift Right	$Rd(n) \leftarrow Rd(n+1), Rd(7) \leftarrow 0$	Z,C,N,V	1
ROL	Rd	Rotate Left through Carry	$Rd(0) \leftarrow C, Rd(n+1) \leftarrow Rd(n), C \leftarrow Rd(7)$	Z,C,N,V	1
ROR	Rd	Rotate Right through Carry	$Rd(7) \leftarrow C, Rd(n) \leftarrow Rd(n+1), C \leftarrow Rd(0)$	Z,C,N,V	1
ASR	Rd	Arithmetic Shift Right	$Rd(n) \leftarrow Rd(n+1), n = 0..6$	Z,C,N,V	1
SWAP	Rd	Swap Nibbles	$Rd(3..0) \leftarrow Rd(7..4), Rd(7..4) \leftarrow Rd(3..0)$	None	1
BSET	s	Flag Set	$SREG(s) \leftarrow 1$	SREG(s)	1
BCLR	s	Flag Clear	$SREG(s) \leftarrow 0$	SREG(s)	1
BST	Rr, b	Bit Store from Register to T	$T \leftarrow Rr(b)$	T	1
BLD	Rd, b	Bit Load from T to Register	$Rd(b) \leftarrow T$	None	1
SEC		Set Carry	$C \leftarrow 1$	C	1
CLC		Clear Carry	$C \leftarrow 0$	C	1
SEN		Set Negative Flag	$N \leftarrow 1$	N	1
CLN		Clear Negative Flag	$N \leftarrow 0$	N	1
SEZ		Set Zero Flag	$Z \leftarrow 1$	Z	1
CLZ		Clear Zero Flag	$Z \leftarrow 0$	Z	1
SEI		Global Interrupt Enable	$I \leftarrow 1$	I	1
CLI		Global Interrupt Disable	$I \leftarrow 0$	I	1
SES		Set Signed Test Flag	$S \leftarrow 1$	S	1
CLS		Clear Signed Test Flag	$S \leftarrow 0$	S	1
SEV		Set Two's Complement Overflow	$V \leftarrow 1$	V	1
CLV		Clear Two's Complement Overflow	$V \leftarrow 0$	V	1
SET		Set T in SREG	$T \leftarrow 1$	T	1
CLT		Clear T in SREG	$T \leftarrow 0$	T	1
SEH		Set Half-carry Flag in SREG	$H \leftarrow 1$	H	1
CLH		Clear Half-carry Flag in SREG	$H \leftarrow 0$	H	1
NOP		No Operation		None	1
SLEEP		Sleep	(see specific descr. for Sleep function)	None	1
WDR		Watchdog Reset	(see specific descr. for WDR/timer)	None	1



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